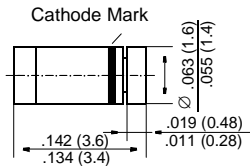


LL103A THRU LL103C

Schottky Diodes

MiniMELF



Dimensions in inches and (millimeters)

FEATURES

- ◆ For general purpose applications.
- ◆ The LL103A, B, C is a metal-on-silicon Schottky barrier device which is protected by a PN junction guard ring.
- ◆ The low forward voltage drop and fast switching make it ideal for protection of MOS devices, steering, biasing and coupling diodes for fast switching and low logic level applications. Other applications are click suppression, efficient full wave bridges in telephone subsets, and blocking diodes in rechargeable low voltage battery systems.
- ◆ This diode is also available in DO-35 case with the type designation SD103A, B, C, and in the SOD-123 case with type designation SD103AW, SD103BW, SD103CW.



MECHANICAL DATA

Case: MiniMELF Glass Case SOD-80C

Weight: approx. 0.05 g

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Value	Unit
Peak Inverse Voltage LL103A LL103B LL103C	V_{RRM} V_{RRM} V_{RRM}	40 30 20	V V V
Power Dissipation (Infinite Heatsink) $T_C = 3/8''$ from Body derates at 4 mW/°C to 0 at 125 °C	P_{tot}	400 ¹⁾	mW
Junction Temperature	T_j	125	°C
Storage Temperature Range	T_S	-55 to +150	°C
Single Cycle Surge 60-Hz Sine Wave	I_{FSM}	15	A

¹⁾ Valid provided that electrodes are kept at ambient temperature.

LL103A THRU LL103C

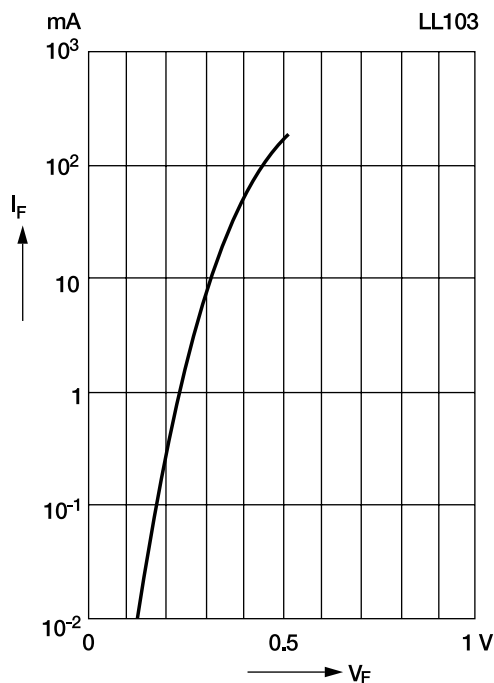
ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

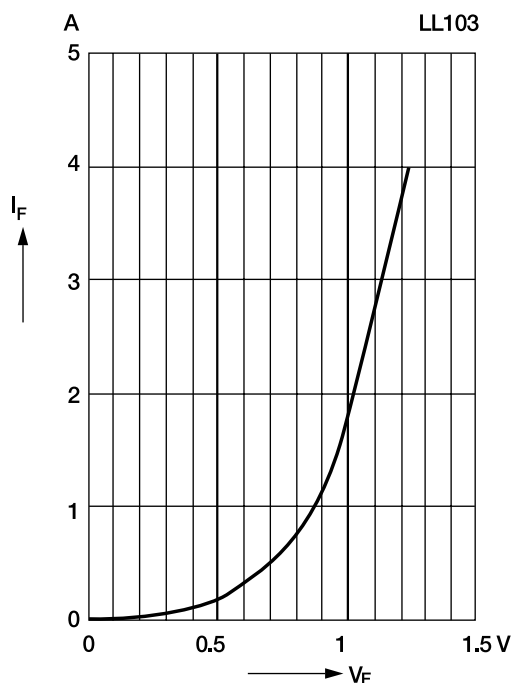
	Symbol	Min.	Typ.	Max.	Unit
Leakage Current at $V_R = 30\text{ V}$ at $V_R = 20\text{ V}$ at $V_R = 10\text{ V}$	I_R I_R I_R	— — —	— — —	5 5 5	μA μA μA
Forward Voltage Drop at $I_F = 20\text{ mA}$ at $I_F = 200\text{ mA}$	V_F V_F	— —	— —	0.37 0.6	V V
Junction Capacitance at $V_R = 0\text{ V}$, $f = 1\text{ MHz}$	C_{tot}	—	50	—	pF
Reverse Recovery Time at $I_F = I_R = 50\text{ mA}$ to 200 mA , recover to $0.1 I_R$	t_{rr}	—	10	—	ns

RATINGS AND CHARACTERISTIC CURVES LL103A THRU LL103C

Typical variation of fwd. current vs. fwd. voltage for primary conduction through the Schottky barrier



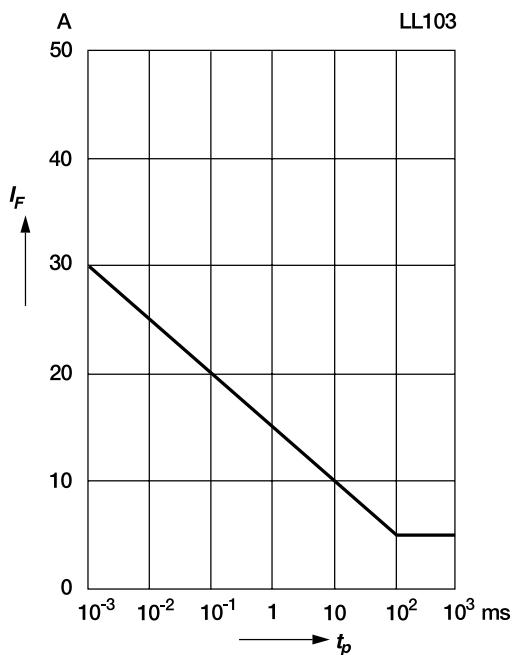
Typical high current forward conduction curve
 $t_p = 300\text{ ms}$, duty cycle = 2%



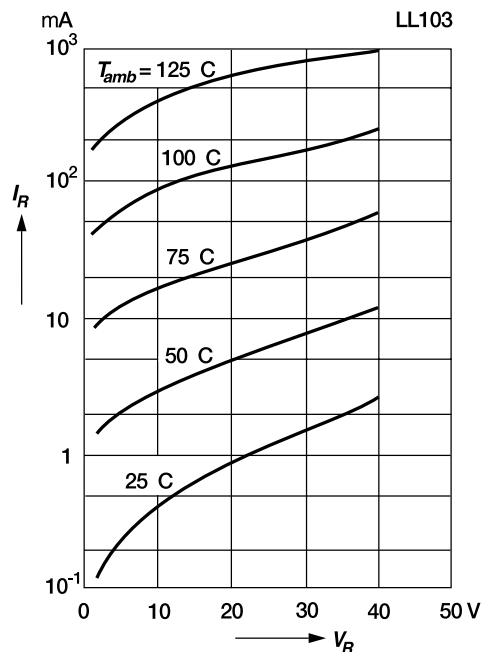
RATINGS AND CHARACTERISTIC CURVES LL103A THRU LL103C

Typical non repetitive forward surge current versus pulse width

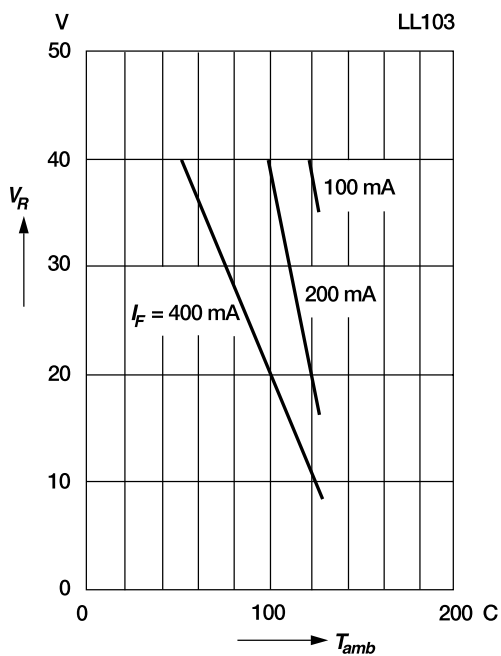
Rectangular pulse



Typical variation of reverse current at various temperatures



Blocking voltage deration versus temperature at various average forward currents



Typical capacitance versus reverse voltage

